Docket No.: 42P17284

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In	Re	the	Application of:

HAI DENG

Art Group:

Application No.:

Examiner:

Filed:

For:

ZEOLITE - SOL GEL

NANO-COMPOSITE LOW K

DIELECTRIC

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted concurrently with the Utility Application. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Please charge any fees due to Deposit Account 02-2666. A duplicate copy of the Fee Transmittal (PTO/SB/17) is enclosed for this purpose.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

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I hereby certify that this correspondence is being deposited with the United States Postal Service on the date shown below with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Patricia M. Richard

Date

Complete if Known Substitute for form 1449A/PTO Application Number INFORMATION DISCLOSURE Filing Date First Named Inventor Hai Deng STATEMENT BY APPLICANT Art Unit (use as many sheets as necessary) **Examiner Name Sheet** 1 of 2 **Attorney Docket Number** 42P17284

U.S. PATENT DOCUMENTS							
Examiner Initials*	Cite No.'	Document Number Number - Kind Code ² (if known)	Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
		US-6,573,131 B2	06-03-2003	Yan, et al.			
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FOREIGN PATENT DOCUMENTS								
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^{&#}x27;Applicant's unique citation designation number (optional). *See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. *Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). *For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. *Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. *Applicant is to place a check mark here if English language Translation is attached.

Substitute for form 1449A/PTO				Co	Complete if Known		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT			CUDE	Application Number			
			SURE	Filing Date			
			CANT	First Named Inventor	Hai Deng		
				Art Unit			
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Sheet	2	of	2	Attorney Docket Number	42P17284		

NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No.¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	ť		
		MORRIS, et al. METHOD OF FABRICATION OF LOW DIELECTRIC CONSTANT POROUS METAL SILICATE FILMS, U.S. Patent Application No. 10/323,988, Filed 12/17/2002, 23 pages.	÷		
		ZHENGBAO WANG, et al., Pure Silica Zeolite Films as Low-k Dielectrics by Spin-On of Nanoparticle Suspensions, Advanced Materials 2001, No. 19, October 2, pp.1463-1466.			
		ZHENGBAO WANG, et al., Silica Zeolite Low-k Dielectric Films, Department of Chemical and Environmental Engineering, University of California, Riverside, 15 pages.	·		
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